# NSN 5961-00-434-2986

Transistor - Page 1 of 1



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## Inclosure Material:

Metal

**Overall Length:** 

0.260 inches

# **Overall Height:**

0.260 inches

# **Overall Diameter:**

0.370 inches

## Mounting Facility Quantity:

2

#### Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 7.0 breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

Between 500.00 milliamperes source cutoff current and 1.00 amperes source cutoff current

#### Power Rating Per Characteristic:

7.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

#### Terminal Type And Quantity:

3 uninsulated wire lead

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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